R_10032 CA-330-11; LDMOS bias module Rev. 2 — 1 September 2015

AMPLEON

Report

Document information

Info	Content
Keywords	LDMOS, bias
Abstract	This report describes a bias module for LDMOS RF power transistors. It provides a low-noise bias supply, temperature compensation, and a very low output impedance to help with video bandwidth optimisation

Revision history

Rev	Date	Description
R_10032#2	20150901	Modifications
		 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.
		• Legal texts have been adapted to the new company name where appropriate.
1.0	20120724	Initial version

Contact information

For more information, please visit: http://www.ampleon.com

For sales office addresses, please visit: http://www.ampleon.com/sales

R_10032#2

Report

1. Introduction

LDMOS RF power transistors require temperature-compensated gate bias voltages to maintain constant quiescent drain currents over temperature. Additionally, the bias source must present a very low frequency to the LDMOS gate across the modulation frequency range ("video bandwidth") to minimize nonlinearity and memory effects.

This report describes a bias module for LDMOS RF power transistors. It provides a low-noise bias supply, temperature compensation, and a very low output impedance to help with video bandwidth optimization.

2. Summary

The characteristics of the bias module described in this report are summarized in Table 1.

Table 1. Summary of bias module characteristics

Parameter	Value
Supply voltage	10 V to 80 V
Supply current	23 mA typical (no-load)
Output voltage	0 V to 3 V ^[1]
Output voltage adjustment range	1.4 V typical
Output voltage temperature compensation	–2 mV/°C typical ^[2]
Output voltage stability	\leq 500 μ V
Output impedance	\leq 2.5 $\Omega,$ DC to 100 MHz
Output voltage noise	\leq 100 μV RMS, 10 Hz to 100 kHz
Output current	70 mA typical
Dimensions	26 mm \times 11 mm \times 8 mm

[1] Resistor values may have to be changed for part of range.

[2] Uses external NPN temperature sensing transistor in contact with heatsink.

3. Circuit description

3.1 Temperature compensation

The quiescent drain current I_{Dq} (and hence the operating point) of the RF device is set by adjusting the gate-source voltage V_{GS} with a constant-voltage bias source. In an LDMOS device, the gate-source threshold voltage $V_{GS(th)}$ is inversely proportional to temperature, with a slope of about $-2 \text{ mV/}^{\circ}\text{C}$. To maintain a constant quiescent current, the voltage generated by the bias supply should vary as a function of the junction temperature T_j of the RF device.

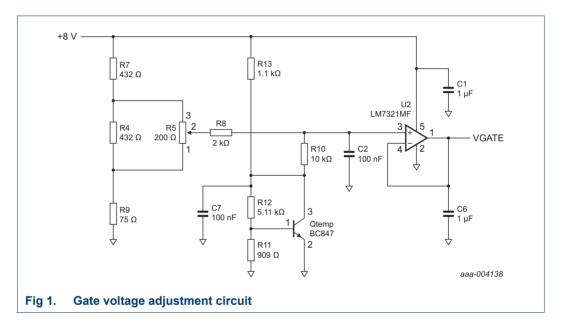
It is difficult to track the junction temperature exactly. However, reasonable results are obtained by monitoring the temperature of the baseplate, which is close to the RF transistor, with the temperature compensated bias circuit used in this amplifier. This circuit is shown in Figure 1.

R_10032#2

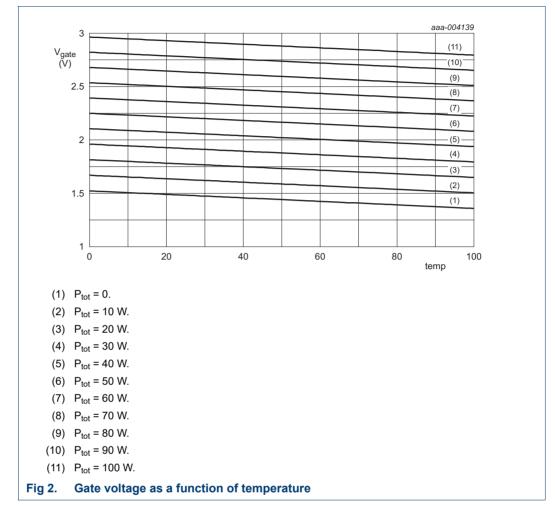
The temperature sensing device (Q_{temp}), is attached to the baseplate near the RF device through a hole in the PCB. Its collector current is proportional to temperature, which results in a collector voltage slope of approximately $-10 \text{ mV}/^{\circ}$ C. Part of this temperature-dependent voltage is summed with the adjustable bias voltage from potentiometer R5 to generate the temperature-compensated final bias voltage.

3.2 Gate voltage adjustment

A variable voltage derived from the 8 V supply is summed with the temperature monitor voltage to generate a temperature-compensated gate voltage. R7 and R9 are selected to set the desired gate voltage trim range, and R10 is selected to provide the desired amount of temperature compensation. Figure 1 shows component values for V_{GS} = 2.2 ± 0.7 V, as given in Figure 2.

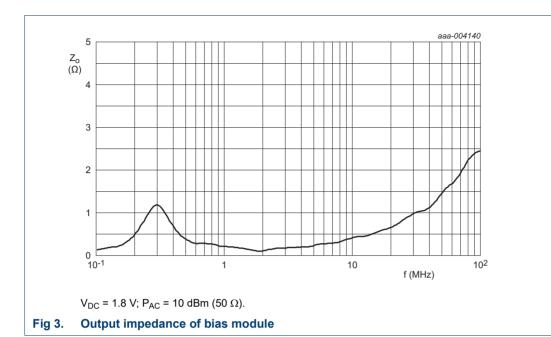


CA-330-11; LDMOS bias module



U2 is a high-current operational amplifier chosen because it is stable with any capacitive load. As shown in Figure 3, the output impedance of the bias source is low (less than 2.5 Ω) because of the feedback around U2. However, practical LDMOS applications may require an additional series gate resistor of 5 Ω to 20 Ω to ensure low-frequency device stability.

AMPLEON



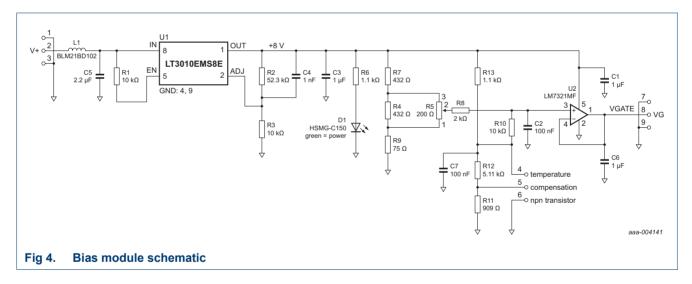


Table 2. Bias module bill of materials

See <u>Figure 5</u> and <u>Figure 6</u> for component layout.

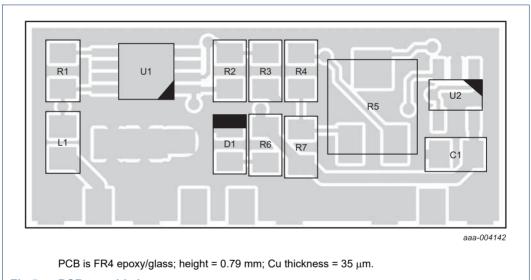
Component	Description	Value	Remarks
C1, C3, C6	capacitor; 50 V 10 % X7R, 0805	1 μF	
C2, C7	capacitor; 50 V 10 % X7R, 0805	100 nF	
C4	capacitor; 100 V 10 % NP0, 0805	1 nF	
C5	capacitor; 100 V 10 % X7R, 1210	2.2 μF	
D1	LED; green, 1206		
L1	ferrite bead; 200 mA, 0805		Murata BLM21BD102SN1D
R1, R3, R10	resistor; 1 % 100 ppm CF, 0805	10.0 kΩ	
R2	resistor; 1 % 100 ppm CF, 0805	52.3 kΩ	
R4, R7	resistor; 1 % 100 ppm CF, 0805	432 Ω	

All information provided in this document is subject to legal disclaimers.

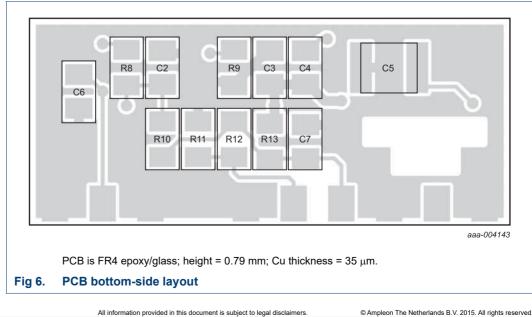
Table 2. Bias module bill of materials ... continued

See Figure 5 and Figure 6 for component layout.

Component	Description	Value	Remarks
R5	potentiometer; 5t cermet	200 Ω	Bourns 3214J-1-201E
R6, R13	resistor; 1 % 100 ppm CF, 0805	1.10 kΩ	
R8	resistor; 1 % 100 ppm CF, 0805	2.00 kΩ	
R9	resistor; 1 % 100 ppm CF, 0805	75 Ω	
R11	resistor; 1 % 100 ppm CF, 0805	909 Ω	
R12	resistor; 1 % 100 ppm CF, 0805	5.11 kΩ	
U1	voltage regulator, 3 V to 80 V adjustable, 50 mA, MSOP8		Linear LT3010EMS8E
U2	Op amp, rail-rail unlimited C _{load} , SOT23-5		National LM7321MF







© Ampleon The Netherlands B.V. 2015. All rights reserved.

4. Abbreviations

Table 3.	Abbreviations
Acronym	Description
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
PCB	Printed-Circuit Board

CA-330-11; LDMOS bias module

5. Legal information

5.1 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Ampleon does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

5.2 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Ampleon does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Ampleon takes no responsibility for the content in this document if provided by an information source outside of Ampleon.

In no event shall Ampleon be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Ampleon' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Ampleon.

Right to make changes — Ampleon reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Ampleon products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Ampleon product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Ampleon and its suppliers accept no liability for inclusion and/or use of Ampleon products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Ampleon makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Ampleon products, and Ampleon accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Ampleon product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Ampleon does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Ampleon products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Ampleon does not accept any liability in this respect.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

5.3 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademark will be replaced by reference to or use of the 'NXP' trademarks.

CA-330-11; LDMOS bias module

6. Contents

1	Introduction 3
2	Summary 3
3	Circuit description 3
3.1	Temperature compensation
3.2	Gate voltage adjustment 4
4	Abbreviations 8
5	Legal information 9
5.1	Definitions
5.2	Disclaimers
5.3	Trademarks 9
6	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© Ampleon The Netherlands B.V. 2015.

All rights reserved.

For more information, please visit: http://www.ampleon.com For sales office addresses, please visit: http://www.ampleon.com/sales

Date of release: 1 September 2015 Document identifier: R_10032#2